

3-phase bridge rectifier + brake chopper + 3-phase bridge inverter SK 100 DGDL 066 T

Preliminary Data

Features

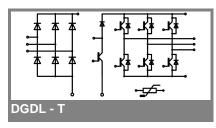
- One screw mounting module
- Fully compatible with SEMITOP®1,2,3
- Improved thermal performances by aluminium oxide substrate
- Trench IGBT technology
- CAL technology free-wheeling diode
- Integrated NTC temperatur sensor

Typical Applications*

- Inverter up to 12,5 kVA
- Typical motor power 5,5 kW

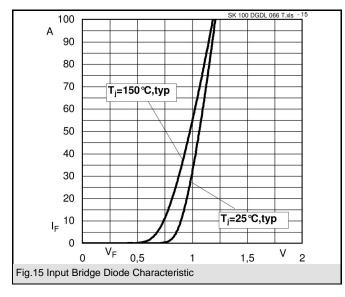
Remarks

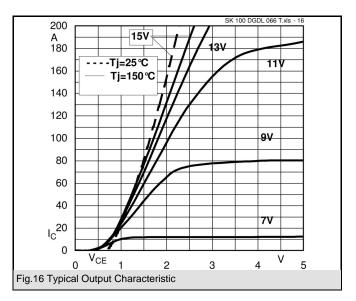
• V_{CE.sat} , V_F = chip level value

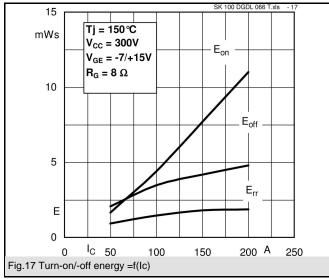


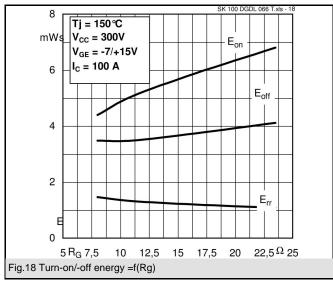
Absolute Maximum Ratings T _s = 25°C, unless otherwise specified							
Symbol	Conditions	Values	Units				
IGBT - Inverter, Chopper							
V _{CES}		600	V				
I _C	$T_s = 25 (70) ^{\circ}C, T_j = 175 ^{\circ}C$	106 (85)	A				
l _C	$T_s = 25 (70) ^{\circ}C, T_j = 150 ^{\circ}C$	96 (73)	Α				
I _{CRM}	$I_{CRM} = 2 \times I_{Cnom}, t_p = 1 \text{ ms}$	200	Α				
V_{GES}		± 20	V				
T _j		-40 + 175	°C				
Diode - Inverter, Chopper							
I _F	$T_s = 25 (70) ^{\circ}C, T_i = 150 ^{\circ}C$	91 (67)	Α				
I _F	$T_s = 25 (70) ^{\circ}C, T_j = 175 ^{\circ}C$	99 (79)	Α				
I _{FRM}	$I_{FRM} = 2xI_{Fnom}, t_p = 1 \text{ ms}$	200	Α				
Diode - Rectifier							
V_{RRM}		800	V				
I _F	T _s = 70 °C	61	Α				
I _{FSM}	t _p = 10 ms, sin 180 °, T _j = 25 °C	700	Α				
i²t	$t_p = 10 \text{ ms, sin } 180 ^\circ, T_j = 25 ^\circ\text{C}$	2400	A²s				
T _j		-40 + 175	°C				
T _{sol}	Terminals, 10 s	260	°C				
T _{stg}		-40 + 125	°C				
V _{isol}	AC, 1 min.	2500	V				

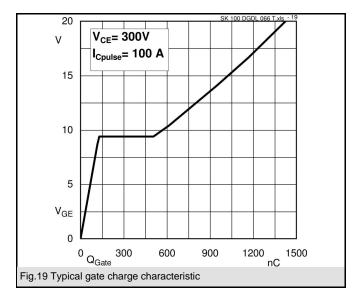
Characte	ristics	T _s = 25°C	T _s = 25°C, unless otherwise specified						
Symbol	Conditions	min.	typ.	max.	Units				
IGBT - Inverter, Chopper									
$V_{CE(sat)} \ V_{GE(th)} \ V_{CE(TO)}$	$I_{Cnom} = 100 \text{ A}, T_j = 25 (150) ^{\circ}\text{C}$ $V_{GE} = V_{CE}, I_C = 1,6 \text{ mA}$ $T_j = 25 (150) ^{\circ}\text{C}$	1,05 5	1,45 (1,7) 5,8 0,9 (0,7)	6,5	V V V				
r_{CE} C_{ies} C_{oes} C_{res}	$T_j^{'}$ = 25 (150) °C V_{CE} = 25 V, V_{GE} = 0 V, f = 1 MHz V_{CE} = 25 V, V_{GE} = 0 V, f = 1 MHz V_{CE} = 25 V, V_{GE} = 0 V, f = 1 MHz		5,5 (10) 6,16 0,38 0,18	9 (13,5)	mΩ nF nF nF				
$R_{th(j-s)}$	per IGBT		0,65		K/W				
$\begin{aligned} & t_{d(on)} \\ & t_r \\ & t_{d(off)} \\ & t_f \\ & E_{on} \left(E_{off} \right) \end{aligned}$	under following conditions $\begin{aligned} &V_{CC} = 300 \text{ V}, V_{GE} = -7 \text{ /} + 15 \text{ V} \\ &I_{Cnom} = 100 \text{ A}, T_j = 150 \text{ °C} \\ &R_{Gon} = R_{Goff} = 8 \Omega \\ &\text{inductive load} \end{aligned}$		28 32 301 45 4,4 (3,5)		ns ns ns ns mJ				
Diode - Inverter, Chopper									
$V_{F} = V_{EC}$ $V_{(TO)}$ r_{T} $R_{th(j-s)}$	$I_F = 100 \text{ A}, T_j = 25 (150) ^{\circ}\text{C}$ $T_j = 25 (150) ^{\circ}\text{C}$ $T_j = 25 (150) ^{\circ}\text{C}$ per diode		1,25 (1,2) 0,95 (0,85) 3 (3,5) 0,8		V V mΩ K/W				
I _{RRM} Q _{rr} E _{rr}	under following conditions $I_{Fnom} = 100 \text{ A}, V_R = 300 \text{ V}$ $V_{GE} = 0 \text{ V}, T_j = 150 ^{\circ}\text{C}$ $di_F/dt = 2438 \text{ A/}\mu\text{s}$		40 5 1,45		Α μC mJ				
Diode - Rectifier									
$V_{F} \\ V_{(TO)} \\ r_{T} \\ R_{th(j-s)}$	$I_{Fnom} = 35 \text{ A, T}_{j} = 25 \text{ °C}$ $T_{j} = 150 \text{ °C}$ $T_{j} = 150 \text{ °C}$ per diode		1,1 0,8 11 0,9		V V mΩ K/W				
	Temperature Sensor								
R _{ts}	5 %, T _r = 25 (100) °C		5000(493)		Ω				
Mechanical Data									
w M _s	Mounting torque	2,5	60	2,75	g Nm				

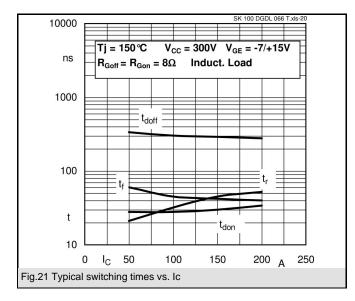


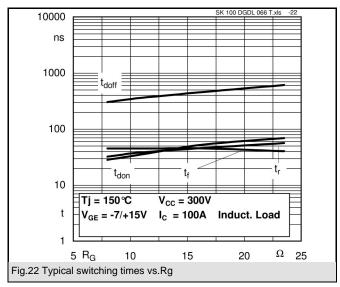


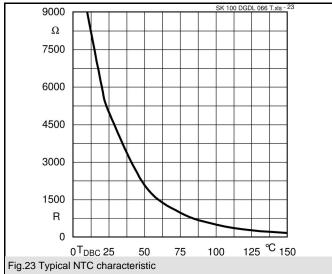


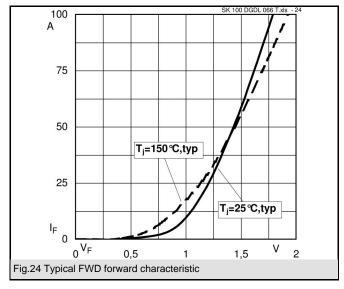




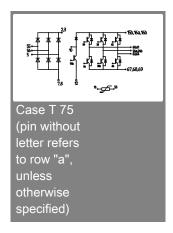


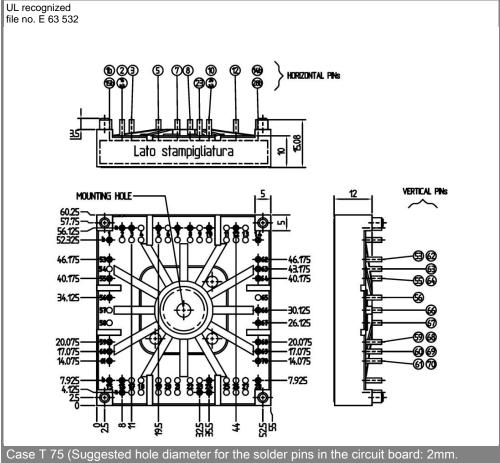






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Case T 75 (Suggested hole diameter for the solder pins in the circuit board: 2mm. Suggested hole diameter for the mounting pins in the circuit board: 3,6mm)

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.